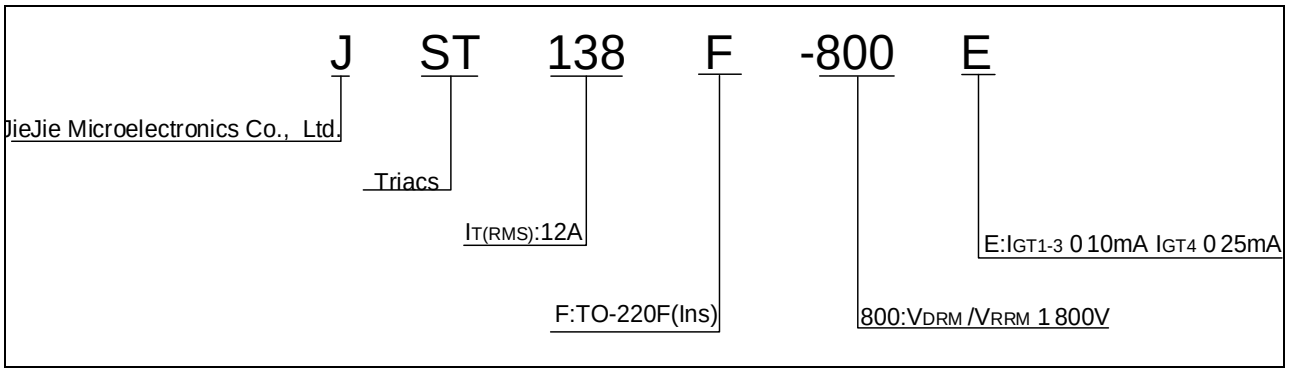
## JST138F-800E 12A TRIAC

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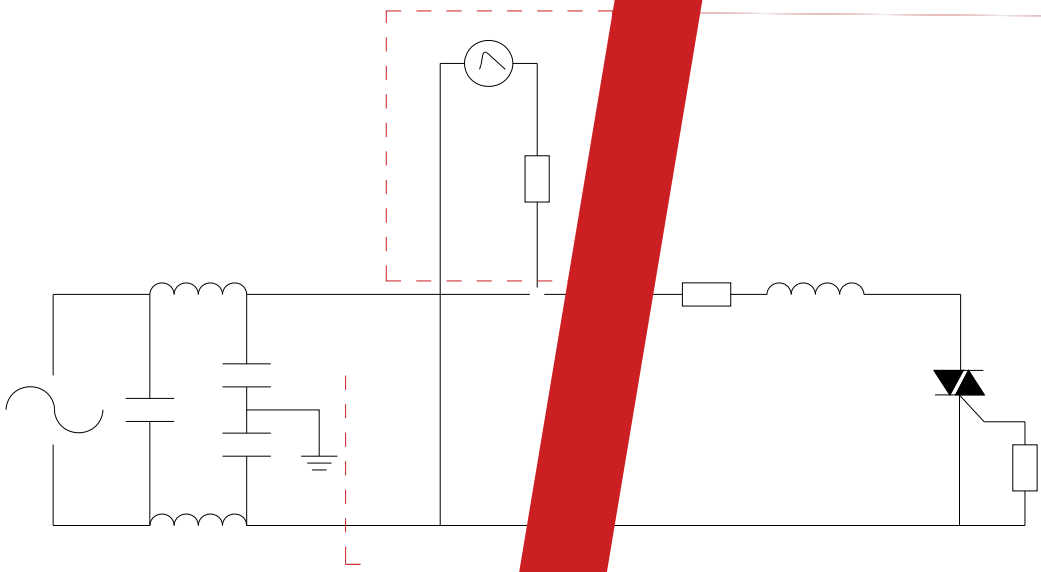

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**FIG.1:** Maximum power dissipation versus RMS on-state current



**FIG.2:** RMS on-state current versus case temperature

FIG.7 ÖTest circuit for inductive and resistive lo o IEC-61000-4-5 standards



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| Order code | Voltage $V_{DRM}/V_{RRM}$ (V) | IGT(mA) | | Package | Base qty. (pcs) | Delivery mode |
|---|---|---|---|---|---|---|
| | | - - | | | | |
| **JST138F-800E** | **800** | **10** | **25** | **TO-220F(Ins)** | **50** | **Tube** |

## Document Revision History

| Date | Revision | Changes |
|---|---|---|
| Apr.14, 2023 | A.1.0 | Last updated |
| Oct.15, 2025 | A.1.1 | Revise PACKAGE MECHANICAL DATA |

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